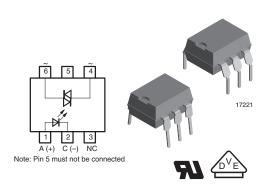


Vishay Semiconductors

Optocoupler, Phototriac Output, 250 V V_{DRM}



DESCRIPTION

The K3010P, K3010PG series consists of a photo-transistor optically coupled to a gallium arsenide infrared-emitting diode in a 6-pin plastic dual inline package

VDE STANDARDS

These couplers perform safety functions according to the following equipment standards:

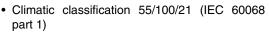
- DIN EN 60747-5-5 (VDE 0884)
 Optocoupler for electrical safety requirements
- IEC 60950/EN 60950
 Office machines (applied for reinforced isolation for mains voltage ≤ 400 V_{RMS})
- VDE 0804
 Telecommunication apparatus and data processing
- IEC 60065
 Safety for mains-operated electronic and related household apparatus

AGENCY APPROVALS

- UL1577, file no. E76222 system code C, double protection
- BSI: BS EN 41003, BS EN 60065 (BS 415), BS EN 60950 (BS 7002), certificate number 7081 and 7402
- DIN EN 60747-5-5 (VDE 0884)
- FIMKO (SETI): EN 60950, certificate no. 12398

FEATURES

- Isolation materials according to UL 94-VO
- Pollution degree 2 (DIN/VDE 0110 resp. IEC 60664)





- Special construction: therefore, extra low coupling capacity of typical 0.2 pF, high common mode rejection
- · IFT offered in 3 groups
- Rated impulse voltage (transient overvoltage)
 V_{IOTM} = 6 kV peak
- Isolation test voltage (partial discharge test) V_{pd} = 1.6 kV
- Creepage current resistance according to VDE 0303/ IEC 60112 comparative tracking index: CTI = 275
- Thickness through insulation ≥ 0.75 mm
- · Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

APPLICATIONS

- Monitors
- · Air conditioners
- · Line switches
- Solid state relay
- Microwave
- Circuits for safe protective separation against electrical shock according to safety class II (reinforced isolation):
 - for appl. class I IV at mains voltage ≤ 300 V
 - for appl. class I III at mains voltage ≤ 600 V according to DIN EN 60747-5-5 (VDE 0884)

ORDER INFORMATION	
PART	REMARKS
K3010P	15 mA, I _{FT} , V _{DRM} = 250 V, DIP-6
K3011P	10 mA, I _{FT} , V _{DRM} = 250 V, DIP-6
K3012P	5 mA, I _{FT} , V _{DRM} = 250 V, DIP-6
K3010PG	15 mA, I _{FT,} V _{DRM} = 250 V, DIP-6 400 mil
K3011PG	10 mA, I _{FT,} V _{DRM} = 250 V, DIP-6 400 mil
K3012PG	5 mA, I _{FT,} V _{DRM} = 250 V, DIP-6 400 mil

Note

For additional information on the available options refer to option information. G = leadform 10.16 mm; G = leadform

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ABSOLUTE MAXIMUM RATINGS (1)								
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT				
INPUT								
Reverse voltage		V_{R}	5	V				
Forward current		l _F	80	mA				
Forward surge current	t _P ≤ 10 μs	I _{FSM}	3	Α				
Power dissipation		P _{diss}	100	mW				
Junction temperature		T _j	100	°C				
OUTPUT								
Off state output terminal voltage		V_{DRM}	250	V				
On state RMS current		I _{TRM}	100	mA				
Peak surge current, non-repetitive	t _p ≤ 10 ms	I _{TMS}	1.5	Α				
Power dissipation		P _{diss}	300	mW				
Junction temperature		T _j	100	°C				
COUPLER								
Isolation test voltage (RMS)	t = 1 min	V_{ISO}	3750	V_{RMS}				
Total power dissipation		P _{tot}	350	mW				
Ambient temperature range		T _{amb}	- 40 to + 85	°C				
Storage temperature range		T _{stg}	- 55 to + 100	°C				
Soldering temperature	2 mm from case, $t \le 10 \text{ s}$	T _{sld}	260	°C				

Notes

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

ELECTRICAL CHARACTERISTICS (1)									
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT		
INPUT	INPUT								
Forward voltage	$I_F = 50 \text{ mA}$		V _F		1.25	1.6	V		
Junction capacitance	$V_R = 0$, $f = 1 MHz$		C _j		50		pF		
OUTPUT									
Forward peak off-state voltage (repetitive)	I _{RDM} = 100 nA		V _{DRM} (2)	250			٧		
Peak on-state voltage	I _{TM} = 100 mA		V _{TM}		1.5	3	V		
Critical rate of rise of off-state voltage	I _{FT} = 0, I _{FT} = 30 mA,		dV/d _{tcr}		10		nA		
Chilical rate of fise of oil-state voltage			dV/d _{tcrq}	0.1	0.2		nA		
COUPLER (3)									
	$V_S = 3 V$, $R_L = 150 \Omega$	K3010P	I _{FT}		8	15	mA		
		K3010PG	I _{FT}		8	15	mA		
Collector emitter saturation voltage		K3011P	I _{FT}		5	10	mA		
Collector emitter saturation voltage		K3011PG	I _{FT}		5	10	mA		
		K3012P	I _{FT}		2	5	mA		
		K3012PG	I _{FT}		2	5	mA		
Holding current	$I_F=10~mA,~V_S\geq 3~V$		I _H		100		μΑ		

Notes

 $^{^{(1)}}$ T_{amb} = 25 °C, unless otherwise specified.

 $^{^{(1)}}$ T_{amb} = 25 $^{\circ}$ C, unless otherwise specified.

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

⁽²⁾ Test voltage must be applied within dV/dt ratings.

⁽³⁾ I_{FT} is defined as a minimum trigger current.



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Vishay Semiconductors

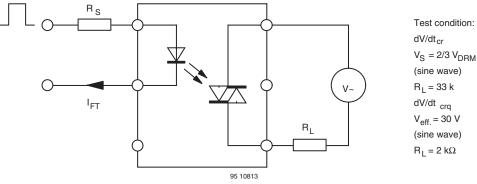
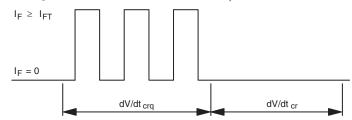


Fig. 1 - Test Circuit for dV/dt_{cr} and dV/dt_{crq}



dV/dt cr

Highest value of the "rate of rise of off-state voltage" which does not cause any switching from the off state to the on state

dV/dt crq

Highest value of the "rate of rise of communicating voltage" which does not switch on the device again, after the voltage has decreased to zero and the trigger current is switched from $I_{\rm FT}$ to zero

95 10814

Fig. 2

+ 5 V 270

O.1 μF

VAC ~

Galvanic seperation

Fig. 3 - Motor Control Circuit

MAXIMUM SAFETY RATINGS							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
INPUT	·	_				•	
Forward current		I _{S, INPUT}			130	mA	
OUTPUT	•						
Power dissipation		P _s , _{OUTPUT}			600	mW	
COUPLER							
Rated transient voltage		V_{IOTM}			6	kV	
Safety temperature		T _{si}			150	°C	
Isolation test voltage		V _{IORM}			848	V	
		V _{IORM}			600	V_{RMS}	

Note

According to DIN EN 60747-5-5 (see figure 4). This optocoupler is suitable for safe electrical isolation only within the safety ratings. Compliance with the safety ratings shall be ensured by means of suitable protective circuits.

Vishay Semiconductors

Optocoupler, Phototriac Output, 250 V V_{DRM}



INSULATION RATED PARAMETERS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Partial discharge test voltage - routine test	100 %, t _{test} = 1 s	V_{pd}	1.6			kV
		V_{IOTM}	6			kV
Partial discharge test voltage - lot test (sample test)	$t_{Tr} = 60 \text{ s}, t_{test} = 10 \text{ s},$ (see figure 5)	V_{pd}	1.3			kV
Insulation resistance	V _{IO} = 500 V	R _{IO}	10 ¹²			Ω
	V _{IO} = 500 V, T _{amb} = 100 °C	R _{IO}	10 ¹¹			Ω
	V _{IO} = 500 V, T _{amb} = 150 °C (construction test only)	R _{IO}	10 ⁹			Ω

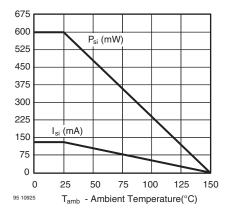


Fig. 4 - Derating Diagram

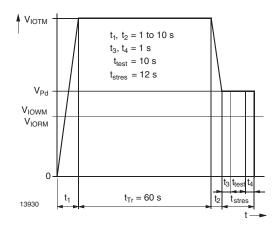


Fig. 5 - Test Pulse Diagram for Sample Test according to DIN EN 60747-5-5/DIN EN 60747-; IEC60747

TYPICAL CHARACTERISTICS

 T_{amb} = 25 °C, unless otherwise specified

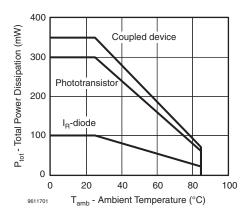


Fig. 6 - Total Power Dissipation vs. Ambient Temperature

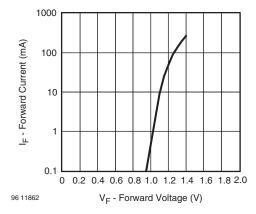


Fig. 7 - Forward Current vs. Forward Voltage



Optocoupler, Phototriac Output, 250 V V_{DRM}

Vishay Semiconductors

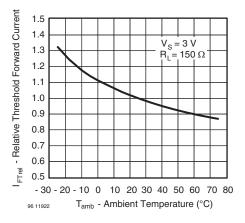


Fig. 8 - Relative Threshold Forward Current vs.
Ambient Temperature

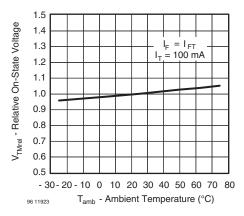


Fig. 9 - Relative On-State vs. Ambient Temperature

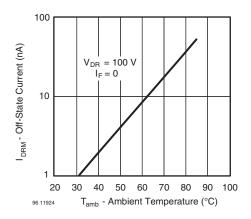


Fig. 10 - Off-State Current vs. Ambient Temperature

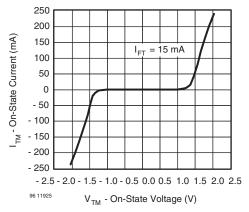
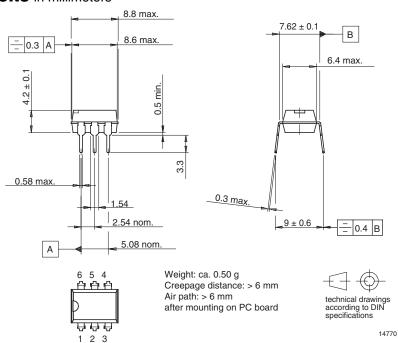


Fig. 11 - Collector Current vs. Forward Current

PACKAGE DIMENSIONS in millimeters

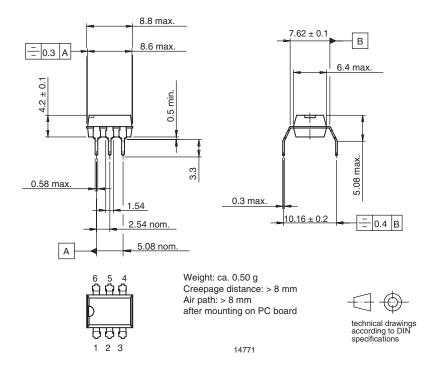


K3010P, K3010PG Series

Vishay Semiconductors

Optocoupler, Phototriac Output, 250 V V_{DRM}









Optocoupler, Phototriac Output, 250 V VDRM

Vishay Semiconductors

OZONE DEPLETING SUBSTANCES POLICY STATEMENT

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively.
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA.
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany

Document Number: 83504 Rev. 1.9, 10-Dec-08



Vishay

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